

PCN Number:	20250129000.1	PCN Date:	February 03, 2025	
Title:	Qualification of RFAB using qualified Process Technology, Die Revision, and additional Assembly site (MLA) & BOM options for select devices			
Customer Contact:	Change Management Team	Dept:	Quality Services	
Proposed 1st Ship Date:	May 04, 2025	Sample requests accepted until:	April 04, 2025*	
*Sample requests received after April 04, 2025 will not be supported.				
Change Type:				
<input checked="" type="checkbox"/>	Assembly Site	<input checked="" type="checkbox"/>	Design	
<input checked="" type="checkbox"/>	Assembly Process	<input checked="" type="checkbox"/>	Data Sheet	
<input checked="" type="checkbox"/>	Assembly Materials	<input type="checkbox"/>	Part number change	
<input type="checkbox"/>	Mechanical Specification	<input type="checkbox"/>	Test Site	
<input checked="" type="checkbox"/>	Packing/Shipping/Labeling	<input type="checkbox"/>	Test Process	
<input type="checkbox"/>		<input type="checkbox"/>	Wafer Bump Material	
<input type="checkbox"/>		<input type="checkbox"/>	Wafer Bump Process	
<input checked="" type="checkbox"/>		<input checked="" type="checkbox"/>	Wafer Fab Site	
<input checked="" type="checkbox"/>		<input checked="" type="checkbox"/>	Wafer Fab Material	
<input checked="" type="checkbox"/>		<input checked="" type="checkbox"/>	Wafer Fab Process	
PCN Details				
Description of Change:				
Texas Instruments is pleased to announce the qualification of its RFAB fabrication facility as an additional Wafer Fab option in addition to an Assembly site (MLA) and BOM options for the devices listed below.				
Current Fab Site		Additional Fab Site		
Fab Site	Process	Wafer Diameter	Fab Site	Process
DL-LIN GFAB6/8	P2CMOS	200 mm 150/200 mm	RFAB	HPA8
				Wafer Diameter
				300 mm
The die was also changed as a result of the process change.				
Construction differences are as follows:				
Group 1 BOM Table (FAB/Process migration, die change plus MLA as new Assembly sit & BOM update – SSOP Packaged devicers				
			TIEM	MLA
Lead Finish			Matte Sn	NiPdAu
Bond Wire composition/diameter			Cu 0.96 mil	Cu, 0.8 mil
Mold Compound			8096859	4226323
Mount Compound			8075531	4147858
Device Marking			NS Logo, pin 1 dot	TI letters, pin 1 dot
Group 2 BOM Table (RFAB/Process migration, die change plus MLA as new Assembly site & BOM update – SOIC Packaged Devices):				
What	TIEM	AP1	MLA	
Bond Wire composition, diameter	Cu, 0.96 mil	Au, 0.9 mil	Cu, 0.8 mil	
Mold Compound	8095179	SID#101323397	4226323	
Mount Compound	8075531	SID#101375281	4147858	

Upon expiry of this PCN, there will be a transition period where TI will combine lead free solutions in a single **standard part number**. For example; **OPA320AQDBVTQ1** – can ship with both Matte Sn and NiPdAu.

Example:

- Customer order for 7500 units of OPA320AQDBVTQ1 with 2500 units SPQ (Standard Pack Quantity per Reel).
- TI can satisfy the above order in one of the following ways.
 - I. 3 Reels of NiPdAu finish.
 - II. 3 Reels of Matte Sn finish
 - III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish.
 - IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.

Datasheet updates are as follows:



Changes from Revision G (April 2013) to Revision H (December 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Moved LMC6035-Q1 to a new document.....	1
• Updated <i>Description</i> text for clarity.....	1
• Updated front-page image.....	1
• Added difference amplifier with RES11 application image.....	1
• Added <i>Pin Configuration and Functions</i>	3
• Updated figures and tables in <i>Pin Configuration and Functions</i>	3
• Added input pin voltage to <i>Absolute Maximum Ratings</i>	5
• Added <i>ESD Ratings</i>	5
• Deleted machine model in <i>ESD Ratings</i>	5
• Added Thermal Information.....	6
• Updated junction-to-ambient thermal resistance values.....	6
• Updated parameter names and symbols.....	7
• Added input voltage noise density specification for $V_+ = 15V$	7
• Changed input current noise density TYP from $0.2fA/\sqrt{Hz}$ to $6fA/\sqrt{Hz}$	7
• Deleted footnotes 1 and 2 from <i>DC Electrical Characteristics</i>	7
• Moved footnotes 4 into open-loop gain test conditions.....	7
• Deleted footnote 1 from <i>AC Electrical Characteristics</i>	7
• Updated footnote 2 and moved conditions to slew rate test conditions.....	7
• Moved footnote 3 from <i>AC Electrical Characteristics</i> conditions crosstalk test conditions.....	7
• Added Figures 5-3, 5-4, 5-17.....	9
• Deleted Figures 16 and 17.....	9
• Added <i>Overview</i>	16
• Added <i>Functional Block Diagram</i>	16
• Changed A_{VOL} to A_{OL}	18
• Updated Figure 7-7.....	20
• Updated Figure 7-8.....	21
• Updated Figure 7-9.....	22
• Changed the value of f_c from 3kHz to 1kHz to fix error in equation.....	22
• Added reference to <i>Measurement and Calibration Techniques for Ultra-low Current Measurement Systems</i> application note in Printed Circuit Board (PCB) Layout for High-Impedance Work.....	23
• Updated thermal resistance information in <i>DSBGA Considerations</i>	24

Product Folder	Current Datasheet Number	New Datasheet Number	Link to full datasheet
LMC603x	SNOS875G	SNOS875H	https://www.ti.com/product/LMC6035

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
<input checked="" type="checkbox"/> No Change			

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
DL-LIN	DLN	USA	Dallas
GFAB6/8	GF6/GF8	GBR	Greenock
RFAB	RFB	USA	Richardson

Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]
A	A

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
TI Melaka	CU6	MYS	Melaka
AP1	AKR	PHL	Cupang, Muntinlupa City
TI Malaysia	MLA	MYS	Kuala Lumpur

Sample product shipping label (not actual product label):

TEXAS INSTRUMENTS
MADE IN: Malaysia
2DC: 20:
MSL 2 /260C/1 YEAR SEAL DT
MSL 1 /235C/UNLIM 03/29/04
OPT:
ITEM: 39
LBL: 5A (L)T0:1750

G4

(Q) 2000 (D) 0336
(31T) LOT: 3959047MLA
(4W) TKY (1T) 7523483SI2
(P)
(2P) REV: (V) 0053317
(20L) CSO: SHE (21L) CCO: USA
(22L) ASO: MLA (23L) ACO: MYS

G3 = Matte Sn
G4 = NiPdAu

Product Affected:

Group 1 Device List (FAB/Process migration, die change plus MLA as new Assembly sit & BOM update – SSOP Packaged devicers):

LMC6035IMM/NOPB	LMC6035IMMX/NOPB	LMC6036IMTX/NOPB
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Group 2 Device List (RFAB/Process migration, die change plus MLA as new Assembly site & BOM update – SOIC Packaged Devices):

LMC6035IMX/NOPB	LMC6036IMX/NOPB
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For alternate parts with similar or improved performance, please visit the product page on TI.com



TI Information
Selective Disclosure

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Name	Condition	Duration	Qual Device: LMC6082IMX/NOPB	QBS Reference: OPA1671IDCKR	QBS Reference: INA849DR	QBS Reference: LMC6482IM/NOPB
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	1/77/0
HAST	A2	Temperature Humidity Bias	85C/85%RH	1000 Hours	-	-	3/231/0	-
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	3/231/0 ¹
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	-
HTOL	B1	Life Test	100C ²	300 Hours	-	-	1/77/0	-
HTOL	B1	Life Test	150C	300 Hours	-	3/231/0	-	3/231/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2397/0 ¹	-	-
ESD	E2	ESD CDM	-	250 Volts	1/3/0	3/9/0	1/3/0	1/3/0
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	3/9/0	1/3/0	1/3/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	3/18/0	1/6/0	1/3/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	1/30/0	3/90/0

- QBS: Qual By Similarity
- Qual Device LMC6082IMX/NOPB is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

TI Qualification ID: R-CHG-2302-065

[1] Lost 3 units.
[2] Tj=150C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Name	Condition	Duration	Qual Device:	QBS Process Reference:	QBS Product Reference:	QBS Package Reference:				
					LMC6035IMMX/NOPB	OPA1671IDCKR	LMC6482MNOB	SN74LV244AQDGSRQ1	SN74LV273AQDGSRQ1	TPS2001EDGKR	TLV1812QDGKRQ1	TLV1822QDGKRQ1
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	1/77/0	1/77/0	1/77/0	1/77/0	1/77/0	-
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	-	1/77/0	1/77/0	1/77/0	-	-
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	-	-	1/77/0	-
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	1/77/0	1/77/0	1/77/0	1/77/0	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	1/45/0	1/45/0	1/77/0	-	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	-	-	-	-	-	-
HTSL	A6	High Temperature Storage Life	175C	500 Hours	-	-	-	-	-	-	1/77/0	-
HTOL	B1	Life Test	125C	1000 Hours	-	-	-	1/77/0	-	-	-	-
HTOL	B1	Life Test	150C	300 Hours	-	3/231/0	3/231/0	-	-	-	1/77/0	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2397/0	-	-	-	-	-	-
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	-	1/15/0	-	-	1/15/0	-
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	-	1/15/0	-	1/22/0	1/15/0	-
PD	C4	Physical Dimensions	Cpk>1.67	-	-	-	-	1/10/0	1/10/0	-	1/10/0	-

Type	#	Test Name	Condition	Duration	Qual Device:	QBS Process Reference:	QBS Product Reference:	QBS Package Reference:				
					LMC6035IMMX/NOPB	OPA1671IDCKR	LMC6482MNOB	SN74LV244AQDGSRQ1	SN74LV273AQDGSRQ1	TPS2001EDGKR	TLV1812QDGKRQ1	TLV1822QDGKRQ1
ESD	E2	ESD CDM	-	250 Volts	1/3/0	3/9/0	1/3/0	-	-	1/3/0	-	-
ESD	E2	ESD CDM	-	500 Volts	-	-	-	1/3/0	1/3/0	-	1/3/0	1/3/0
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	3/9/0	1/3/0	-	-	1/3/0	-	-
ESD	E2	ESD HBM	-	2000 Volts	-	-	-	1/3/0	1/3/0	-	1/3/0	1/3/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	3/18/0	1/3/0	1/6/0	1/6/0	1/3/0	1/6/0	1/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	3/90/0	1/30/0	1/30/0	-	1/30/0	1/30/0

- QBS: Qual By Similarity, also known as Generic Data
- Qual Device LMC6035IMMX/NOPB is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

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TI Qualification ID: R-CHG-2310-040

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Name	Condition	Duration	Qual Device: LMC6084AIMX	QBS Process Reference:	QBS Package Reference:	QBS Package Reference:	QBS Package Reference:
						OPA1671IDCKR	LMC6482IM/NOPB	ULQ2003AQDRQ1	OPA4991QDRQ1
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	1/77/0	3/231/0	3/231/0
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	-	3/231/0	3/231/0
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	-
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0	1/77/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	3/135/0	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	-	-	-
HTSL	A6	High Temperature Storage Life	175C	500 Hours	-	-	-	-	1/45/0
HTOL	B1	Life Test	125C	1000 Hours	-	-	-	3/231/0	-
HTOL	B1	Life Test	150C	300 Hours	-	3/231/0	3/231/0	-	-
HTOL	B1	Life Test	150C	408 Hours	-	-	-	-	1/77/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2397/0	-	-	-

Type	#	Test Name	Condition	Duration	Qual Device: LMC6084AIMX	QBS Process Reference:	QBS Package Reference:	QBS Package Reference:	QBS Package Reference:
						OPA1671IDCKR	LMC6482IM/NOPB	ULQ2003AQDRQ1	OPA4991QDRQ1
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	-	1/15/0	-
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	-	1/15/0	-
ESD	E2	ESD CDM	-	1500 Volts	-	-	-	-	1/3/0
ESD	E2	ESD CDM	-	250 Volts	1/3/0	3/9/0	1/3/0	-	-
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	3/9/0	1/3/0	-	-
ESD	E2	ESD HBM	-	2000 Volts	-	-	-	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	1/3/0	3/18/0	1/3/0	-	1/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	3/90/0	3/90/0	3/90/0

- QBS: Qual By Similarity
- Qual Device LMC6084AIMX is qualified at MSL1 260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

TI Qualification ID: R-CHG-2303-017



TI Information
Selective Disclosure

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Name	Condition	Duration	Qual Device: LMC6036IMTX/NOPB	QBS Reference: OPA1671DCKR	QBS Reference: LMC6482IM/NOPB	QBS Reference: OPA4205APWR
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	1/77/0	3/231/0
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	3/231/0	3/231/0	3/231/0
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	1/77/0	3/231/0	3/231/0	3/231/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	-	3/231/0
HTOL	B1	Life Test	150C	300 Hours	-	3/231/0	3/231/0	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2397/0	-	-
ESD	E2	ESD CDM	-	250 Volts	1/3/0	3/9/0	1/3/0	1/3/0
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	3/9/0	1/3/0	-
LU	E4	Latch-Up	Per JESD78	-	1/3/0	3/18/0	1/3/0	1/3/0
CHAR	E5	Electrical Characterization	Min, Typ, Max Temp	-	1/30/0	3/90/0	3/90/0	1/30/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	3/90/0	1/30/0

- QBS: Qual By Similarity, also known as Generic Data
- Qual Device LMC6036IMTX/NOPB is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

TI Qualification ID: R-CHG-2401-082

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